N-Channel Silicon MOSFET



2SK1813

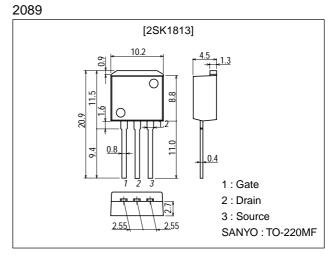
High-Speed Switching Applications

Features

- · Low ON resistance.
- · Ultrahigh-speed switching.
- \cdot Converters.

Package Dimensions

unit:mm



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		100	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	۱ _D		30	A
Drain Current (pulse)	I _{DP}	PW≤10µs, duty cycle≤1%	120	A
Allowable Power Dissipation	PD		1.65	W
		Tc=25°C	70	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Symbol	Conditions	Ratings			Unit
		min	typ	max	Onit
VDSS	I _D =1mA, V _{GS} =0	100			V
IDSS	V _{DS} =100V, V _{GS} =0			100	μA
IGSS	V _{GS} =±20V, V _{DS} =0			±100	nA
VGS(off)	V _{DS} =10V, I _D =1mA	1.5		2.5	V
yfs	V _{DS} =10V, I _D =20A	13	22		S
R _{DS(on)}	I _D =20A, V _{GS} =10V		0.040	0.055	Ω
	VDSS IDSS IGSS VGS(off) yfs	VDSS ID=1mA, VGS=0 IDSS VDS=100V, VGS=0 IGSS VGS=±20V, VDS=0 VGS(off) VDS=10V, ID=1mA yfs VDS=10V, ID=20A	VDSS ID=1mA, VGS=0 100 IDSS VDS=100V, VGS=0 100 IGSS VGS=±20V, VDS=0 100 VGS(off) VDS=10V, ID=1mA 1.5 yfs VDS=10V, ID=20A 13	Symbol Conditions min typ VDSS ID=1mA, VGS=0 100 100 IDSS VDS=100V, VGS=0 100 100 IGSS VGS=±20V, VDS=0 100 100 VGS(off) VDS=10V, ID=1mA 1.5 1100 I yfs VDS=10V, ID=20A 13 22	Symbol Conditions min typ max VDSS ID=1mA, VGS=0 100

(Note) Be careful in handling the 2SK1813 because it has no protection diode between gate and source.

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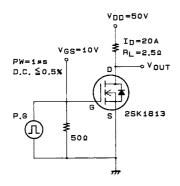
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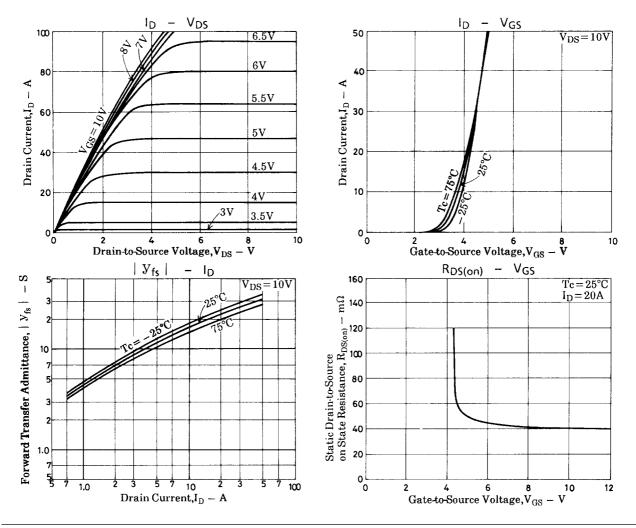
SANYO Electric Co., Ltd. Semiconductor Company TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

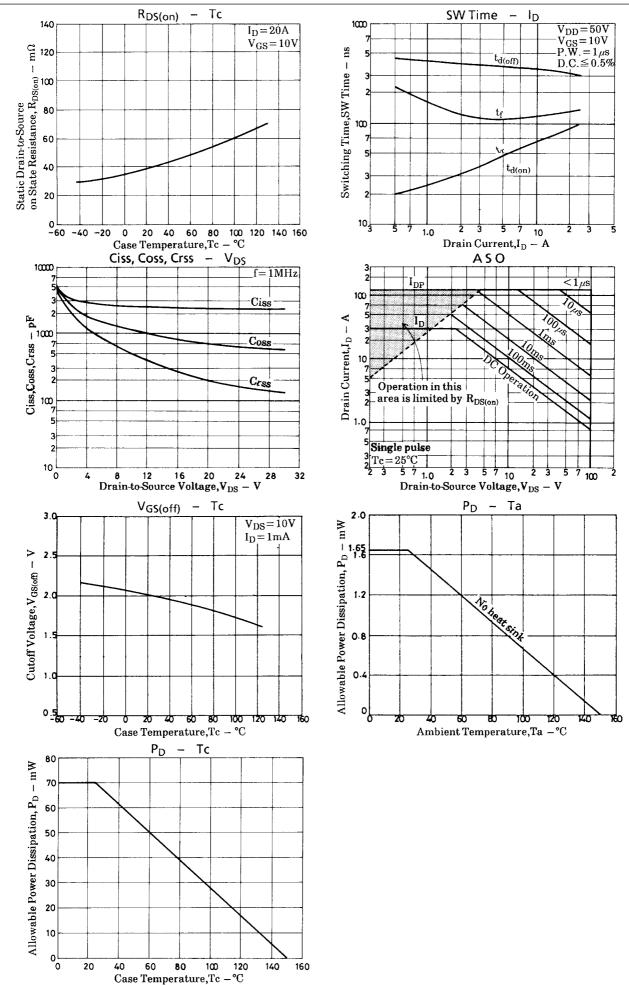
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Parameter	Symbol	Conditions	Ratings			Unit
Input Capacitance	Ciss	V _{DS} =20V, f=1MHz	2	2400		pF
Output Capacitance	Coss	V _{DS} =20V, f=1MHz		700		pF
Reverse Transfer Capacitance	Crss	V _{DS} =20V, f=1MHz		200		pF
Turn-ON Delay Time	t _{d(on)}	I _D =20A, V _{GS} =10V, V _{DD} =50V, R _{GS} =50Ω		30		ns
Rise Time	tr	I _D =20A, V _{GS} =10V, V _{DD} =50V, R _{GS} =50Ω		90		ns
Turn-OFF Delay Time	td(off)	I _D =20A, V _{GS} =10V, V _{DD} =50V, R _{GS} =50Ω		320		ns
Fall Time	tf	I _D =20A, V _{GS} =10V, V _{DD} =50V, R _{GS} =50Ω		130		ns
Diode Forward Voltage	V _{SD}	IF=30A, VGS=0			1.8	V

Switching Time Test Circuit







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